

# PC725V0NSZX Series

DIP 6 pin Darlington Phototransistor output, High Collector-emitter Voltage, High Power Photocoupler

#### ■ Description

**PC725V0NSZX Series** contains an IRED optically coupled to a phototransistor.

It is packaged in a 6 pin DIP, available in SMT gullwing lead-form option.

Input-output isolation voltage(rms) is 5.0kV.

Collector-emitter voltage is 300V, CTR is MIN. 1 000% at input current of 1mA and collector power dissipation is 300mW.

#### ■ Features

- 1. 6 pin DIP package
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. High collector-emitter voltage (V<sub>CEO</sub>:300V)
- 4. Darlington phototransistor output (CTR : MIN. 1 000% at  $I_F=1mA$ ,  $V_{CE}=2V$ )
- 5. Large collector power dissipation (Pc:300mW)
- 6. High isolation voltage between input and output (V<sub>iso(rms)</sub>: 5.0kV)

#### ■ Agency approvals/Compliance

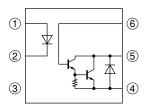
- Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. PC725V)
- 2. Approved by TÜV (VDE0884) (as an option) file No. R-9151576 (as model No. **PC725V**)
- 3. Package resin: UL flammability grade (94V-0)

#### **■** Applications

- 1. Home appliances
- 2. Programmable controllers
- 3. Personal computer peripherals



#### ■ Internal Connection Diagram

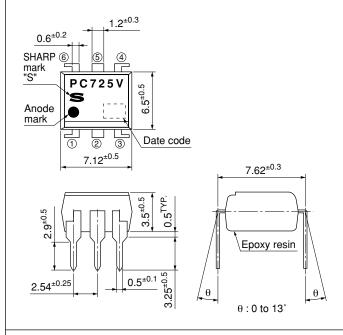


- 1 Anode
- ② Cathode
- ③ NC
- 4 Emitter
- ⑤ Collector
- 6 Base

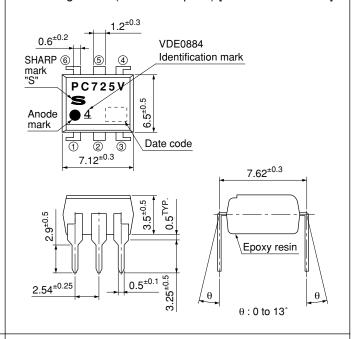
#### **■** Outline Dimensions

(Unit: mm)

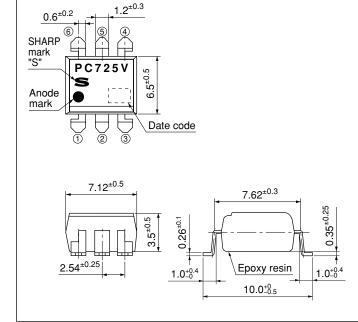
### 1. Through-Hole [ex. PC725V0NSZX]



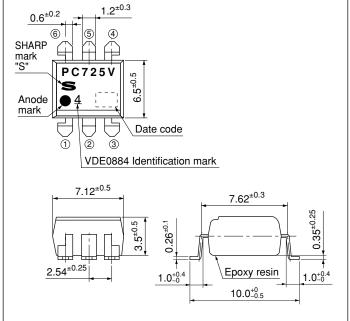
#### 2. Through-Hole (VDE0884 option) [ex. PC725V0YSZX]



#### 3. SMT Gullwing Lead-Form [ex. PC725V0NIPX]

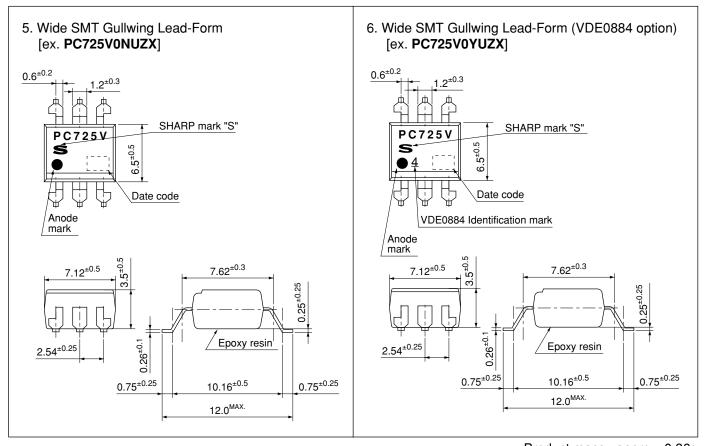


# 4. SMT Gullwing Lead-Form (VDE0884 option) [ex. **PC725V0YIPX**]





(Unit: mm)



Product mass: approx. 0.36g



# Date code (2 digit)

	1st o	digit		2nd digit		
	Year of p	roduction		Month of production		
A.D.	Mark	A.D	Mark	Month	Mark	
1990	A	2002	P	January	1	
1991	В	2003	R	February	2	
1992	С	2004	S	March	3	
1993	D	2005	T	April	4	
1994	Е	2006	U	May	5	
1995	F	2007	V	June	6	
1996	Н	2008	W	July	7	
1997	J	2009	X	August	8	
1998	K	2010	A	September	9	
1999	L	2011	В	October	0	
2000	M	2012	С	November	N	
2001	N	:	:	December	D	

repeats in a 20 year cycle

Country of origin Japan



■ Absolute Maximum Ratings

	<b>Absolute Maximum Ratings</b> $(T_a=25^{\circ}C)$								
	Parameter	Symbol	Rating	Unit					
	Forward current	$I_{\mathrm{F}}$	50	mA					
Input	*1 Peak forward current	$I_{FM}$	1	A					
Inj	Reverse voltage	$V_R$	6	V					
	Power dissipation	P	70	mW					
	Collector-emitter voltage	$V_{CEO}$	300	V					
	Collector-base voltage	$V_{CBO}$	300	V					
Output	Emitter-base voltage	Emitter-base voltage V <sub>EBO</sub>	6	V					
Om	Collector current	$I_C$	150	mA					
	Collector current (reverse)	$-I_{\rm C}$	10	mA					
	Collector power dissipation	$P_{C}$	300	mW					
Total power dissipation Operating temperature Storage temperature		P <sub>tot</sub>	350	mW					
		$T_{opr}$	-25 to +100	°C					
		$T_{stg}$	-40 to +125	°C					
*2 Isolation voltage		V <sub>iso (rms)</sub>	5	kV					
*3 (	Soldering temperature	$T_{sol}$	260	°C					

<sup>\*1</sup> Pulse width≤100μs, Duty ratio: 0.001 \*2 40 to 60%RH, AC for 1minute, f=60Hz \*3 For 10s

# **■** Electro-optical Characteristics

 $(T_a=25^{\circ}C)$ 

	•						(1a-23 C)	
Parameter			Symbol	Conditions	MIN.	TYP.	MAX.	Unit
	Forward voltage		$V_F$	$I_F=10mA$	_	1.2	1.4	V
Immyst	Peak forward voltage		$V_{FM}$	$I_{FM}=0.5V$	_	_	3.0	V
Input	Reverse curre	nt	$I_R$	$V_R=4V$	-	-	10	μΑ
	Terminal capa	citance	Ct	V=0, f=1kHz	_	30	250	pF
	Collector dark	current	I <sub>CEO</sub>	V <sub>CE</sub> =200V, I <sub>F</sub> =0	_	-	1 000	nA
Outmut	Collector-emitter breakdown voltage		BV <sub>CEO</sub>	$I_{C}=0.1 \text{mA}, I_{F}=0$	300	-	-	V
Output	Emitter-base breakdown voltage		$BV_{EBO}$	$I_{E}=10\mu A, I_{F}=0$	6	-	-	V
	Collector-base breakdown voltage		$BV_{CBO}$	$I_{C}=0.1 \text{mA}, I_{F}=0$	300	-	-	V
	Current transfer ratio		$I_{C}$	$I_F=1$ mA, $V_{CE}=2$ V	10	40	150	mA
	Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	$I_F=20mA, I_C=100mA$	-	-	1.2	V
Transfer	Isolation resistance		R <sub>ISO</sub>	DC500V, 40 to 60%RH	5×10 <sup>10</sup>	1×10 <sup>11</sup>	-	Ω
charac-	Floating capacitance		$C_{\mathrm{f}}$	V=0, f=1MHz	_	0.6	1.0	pF
teristics	Cut-off frequency		$f_C$	$V_{CE}$ =2V, $I_{C}$ =20mA, $R_{L}$ =100 $\Omega$ -3dB	1	7	-	kHz
	Dagmanga tima	Rise time	t <sub>r</sub>	V 2V I 20m A B 1000	_	100	300	μs
	Response time	Fall time	$t_{\mathrm{f}}$	$V_{CE}$ =2 $V$ , $I_{C}$ =20 $m$ A, $R_{L}$ =100 $\Omega$	_	20	100	μs



# **■** Model Line-up

Lead Form	Throug	h-Hole	SMT Gullwing				Wide SMT Gullwing		
Doolsooo	Sleeve				Taping				
Package		50pcs/sleeve				1 000pcs/reel			
VDE0884	—— Approved			Approved	—— Approved			Approved	
Model No.	PC725V0NSZX	PC725V0YSZX	PC725V0NIZX	PC725V0YIZX	PC725V0NIPX	PC725V0YIPX	PC725V0NUZX	PC725V0YUZX	

Please contact a local SHARP sales representative to inquire about production status and Lead-Free options.

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Fig.1 Forward Current vs. Ambient Temperature

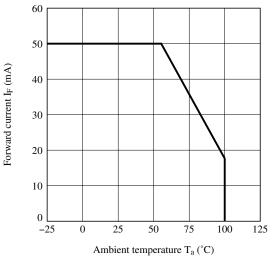


Fig.3 Collector Power Dissipation vs. Ambient Temperature

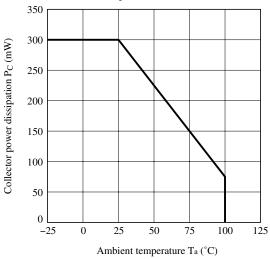


Fig.5 Peak Forward Current vs. Duty Ratio

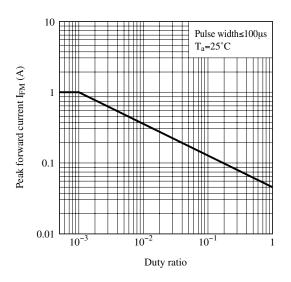


Fig.2 Diode Power Dissipation vs. Ambient Temperature

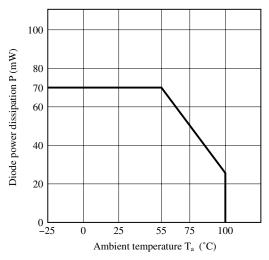


Fig.4 Total Power Dissipation vs. Ambient Temperature

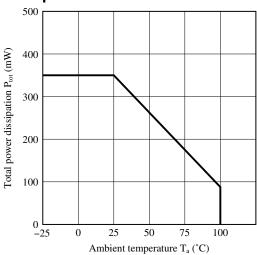


Fig.6 Forward Current vs. Forward Voltage

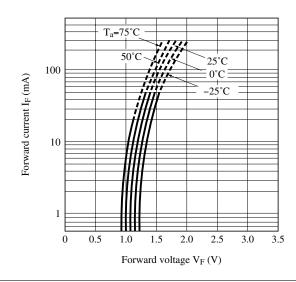




Fig.7 Current Transfer Ratio vs. Forward Current

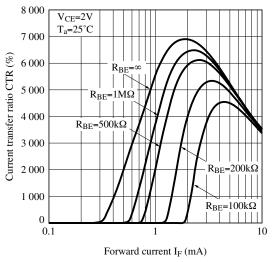


Fig.9 Relative Current Transfer Ratio vs.
Ambient Temperature

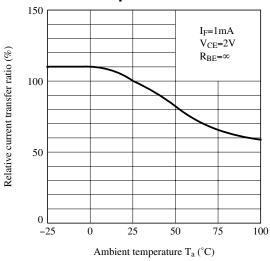


Fig.11 Collector Dark Current vs. Ambient Temperature

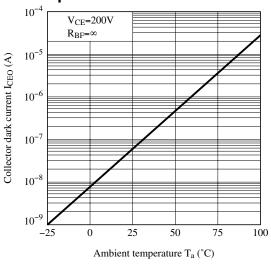


Fig.8 Collector Current vs. Collector-emitter Voltage

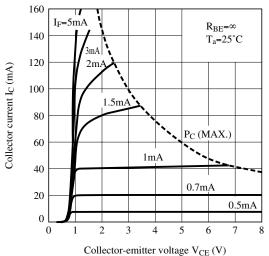


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

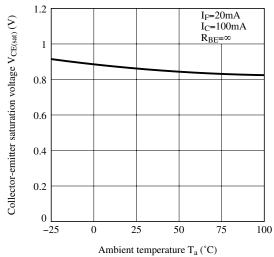
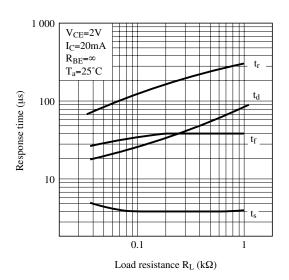


Fig.12 Response Time vs. Load Resistance



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Fig.13 Test Circuit for Response Time

# N<sub>CC</sub> Input Output Output Output Output t<sub>d</sub> t<sub>r</sub> t<sub>r</sub>

Please refer to the conditions in Fig.12

Fig.14 Frequency Response

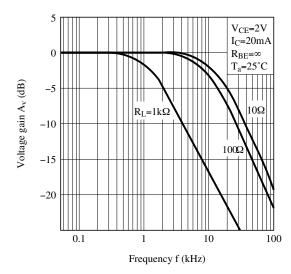
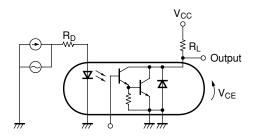


Fig.15 Test Circuit for Frequency Response



Please refer to the conditions in Fig.14

Remarks: Please be aware that all data in the graph are just for reference and not for guarantee.



#### ■ Design Considerations

# Design guide

While operating at I<sub>F</sub><1.0mA, CTR variation may increase.

Please make design considering this fact.

This product is not designed against irradiation and incorporates non-coherent IRED.

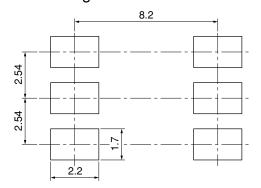
# Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

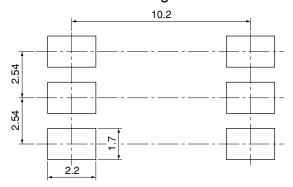
In the case of long term operation, please take the general IRED degradation (50% degradation over 5years) into the design consideration.

#### Recommended Foot Print (reference)

#### SMT Gullwing lead-form



# Wide SMT Gullwing lead-form



(Unit:mm)

<sup>☆</sup> For additional design assistance, please review our corresponding Optoelectronic Application Notes.



#### ■ Manufacturing Guidelines

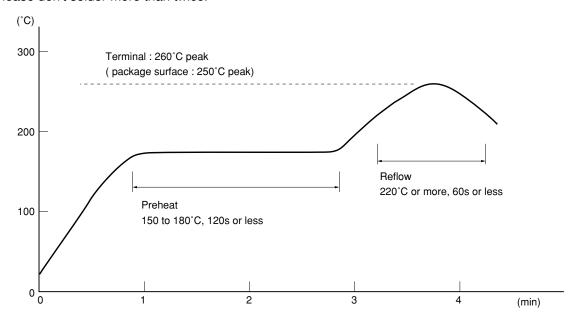
#### Soldering Method

#### Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



#### Flow Soldering:

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

#### Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

#### Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



#### Cleaning instructions

#### Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3minutes or less

#### Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

#### Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

#### Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this device.

Regulation substances:CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

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# ■ Package specification

#### Sleeve package

Package materials

Sleeve: HIPS (with anti-static material)

Stopper: Styrene-Elastomer

# Package method

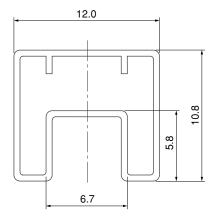
MAX. 50 pcs. of products shall be packaged in a sleeve.

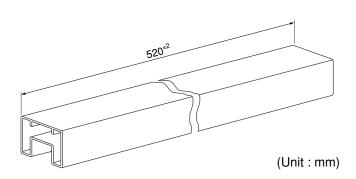
Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

#### Sleeve outline dimensions





(Unit: mm)



# ● Tape and Reel package

# 1. SMT Gullwing

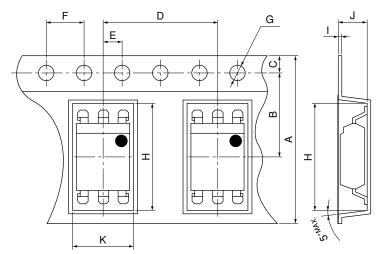
Package materials

Carrier tape: A-PET (with anti-static material)

Cover tape: PET (three layer system)

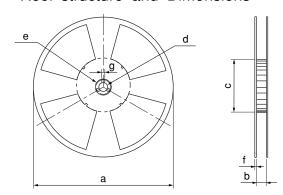
Reel: PS

#### Carrier tape structure and Dimensions



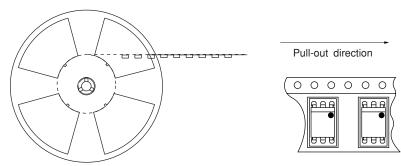
Dimension	(Unit:mm)					
A	В	C	D	Е	F	G
16.0±0.3	7.5 <sup>±0.1</sup>	1.75 <sup>±0.1</sup>	12.0 <sup>±0.1</sup>	2.0 <sup>±0.1</sup>	4.0 <sup>±0.1</sup>	φ1.5 <del>-</del> 8.1
Н	I	J	K			
10.4 <sup>±0.1</sup>	0.4 <sup>±0.05</sup>	4.2 <sup>±0.1</sup>	7.8 <sup>±0.1</sup>			

# Reel structure and Dimensions



Dimensio	ns List	(U	nit : mm)
a	b	c	d
330	330 17.5 <sup>±1.5</sup>		13 <sup>±0.5</sup>
e	f	g	
23±1.0	2.0±0.5	2.0±0.5	

# Direction of product insertion



[Packing: 1 000pcs/reel]



# 2. Wide SMT Gullwing

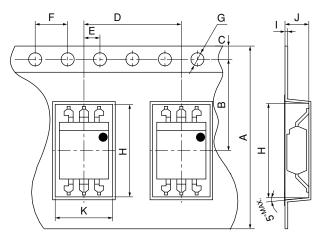
Package materials

Carrier tape: A-PET (with anti-static material)

Cover tape: PET (three layer system)

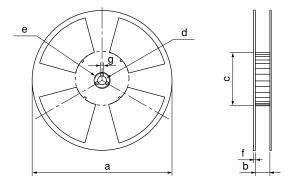
Reel: PS

# Carrier tape structure and Dimensions



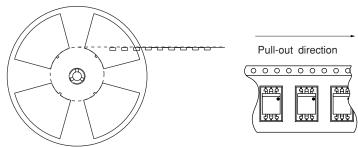
Dimensior	(U	nit: mm)				
A	В	C	D	Е	F	G
24.0 <sup>±0.3</sup>	11.5 <sup>±0.1</sup>	1.75 <sup>±0.1</sup>	12.0 <sup>±0.1</sup>	2.0 <sup>±0.1</sup>	4.0 <sup>±0.1</sup>	φ1.5 <del>+</del> 8.1
Н	I	J	K			
12.2 <sup>±0.1</sup>	0.4±0.05	4.1 <sup>±0.1</sup>	7.6 <sup>±0.1</sup>			

#### Reel structure and Dimensions



Dimensio	ns List	(Unit: mm)			
a	b	c	d		
330	25.5 <sup>±1.5</sup>	100±1.0	13±0.5		
e f		g			
23±1.0	2.0 <sup>±0.5</sup>	2.0 <sup>±0.5</sup>			

# Direction of product insertion



[Packing: 1 000pcs/reel]



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  - --- Consumer electronics
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- --- Alarm equipment
- --- Various safety devices, etc.
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